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Seven indicators variations for multiple PV array configurations under partial shading and faulty PV conditions 3

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8 Abstract

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9 The goal of this paper is to model, compare and analyze the performance of multiple photovoltaic (PV) 10 array configurations under various partial shading and faulty PV conditions. For this purpose, a multiple 11 PV array configurations including series (S), parallel (P), series-parallel (SP), total-cross-tied (TCT) and 12 bridge-linked (BL) are carried out under several partial shading conditions such as, increase or decrease in 13 the partial shading on a row of PV modules and increase or decrease in the partial shading on a column of 14 PV modules. Additionally, in order to test the performance of each PV configuration under faulty PV 15 conditions, from 1 to 6 Faulty PV modules have been disconnected in each PV array configuration. 16 Several indicators such as short circuit current (Isc), current at maximum power point (Impp), open circuit voltage (V_{oc}), voltage at maximum power point (V_{mpp}), series resistance (R_s), fill factor (FF) and thermal 17 18 voltage (V_{te}) have been used to compare the obtained results from each partial shading and PV faulty 19 condition applied to the PV system. MATLAB/Simulink software is used to perform the simulation and 20 the analysis for each examined PV array configuration.

21 Keywords: Multiple PV array configurations, Partial shading, Fault detection, MATLAB/Simulink

22 1. Introduction

23 Growing interest in renewable energy resources has caused the photovoltaic (PV) power market to expand 24 rapidly. The power produced by grid-connected photovoltaic (GCPV) plants depends on various 25 conditions such as PV module's temperature and irradiance level. Shading by the surroundings directly 26 effects both the cell temperature and irradiance level incident on the GCPV systems [1]. There are 27 multiple reasons for the shading affects GCPV systems. K. Lappalainen & S. Valkealahti [2] discussed 28 the output power variations of different PV array configurations during irradiance transition caused by 29 moving cloud. The results shows that the average rate of change in the output power during irradiance 30 transitions is around 3%, where the maximum rate of change is approximate to 75%. Furthermore, an 31 accurate approach method to simulate the characteristics output of a PV systems under either partial 32 shading or mismatch conditions is proposed by J. Bai et al [3]. The method is using the analysis of the 33 current-voltage (I-V) and power-voltage (P-V) curves for various PV systems.

34 A highly detailed PV array model is developed by M. Vincenzo et al [4], the PV model was developed 35 under non-uniform irradiance conditions using PSpice. The model assumed that the PV cells temperature 36 are homogenous for each PV module which makes the simulation and modelling of the PV system less 37 complex. The output results shows a good agreement between the simulation model vs. outdoor 38 experimental results. The losses associated to shading effect can be reduced by using several approaches 39 such as the maximum power point tracking (MPPT) techniques that allow the extension of the global 40 maximum power point. R. Yeung et al [5] proposed a global MPPT algorithm which is based on 41 extracting the power-voltage characteristics of the PV string through varying the input power impedance.

42 PV array configurations which is considered in this paper is one of solutions that can significantly reduce 43 mismatch and shading losses in GCPV plants. It is based on the PV array interconnections of PV modules 44 which are series (S), parallel (P), series-parallel (SP), total-cross-tied (TCT) and bridge-linked (BL) and 45 many other configurations. Several attempts were proposed by researchers to study and analyze the effect 46 of shading on different PV array configuration in order to reduce mismatch losses and providing the 47 maximum output power generation. These attempts can be illustrated by the following:

- 48 1. <u>Comparison of various PV array configurations:</u>
- 49 F. Belhachat & C. Larbes [6] detailed a brief comparison between five different PV array 50 configurations (S, P, SP, TCT and BL configurations). The analysis is based on 51 MATLAB/Simulink software. The results prove that TCT configuration achieved the optimum 52 output power performance under most shading conditions. Moreover, [7] shows a mathematical 53 analysis of TCT PV array configuration under partial shading conditions and its comparison with 54 other PV array configurations such as BL and honey-comb (HC) configurations. Y. Wang & P. 55 Hsu [8] found again that in most cases TCT configuration has a superior performance over the 56 other PV array configurations such as S, P and SP. Some other publications are based on a 57 comprehensive review on PV array configuration under partial shading conditions such as [9 & 58 10].
 - 2. <u>New proposed PV array configuration:</u>

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85 86 S. Pareek & R. dahiya [11] proposed a new method that allows the distribution of shading effect evenly in each PV row thereby enhance the PV array output power. The PV characteristics curves for the proposed method is much smoother than other PV array configurations such as TCT. Furthermore, B. Rani et al [12] suggested a new method for increasing the power generation from PV array configuration. In the proposed approach, the physical location of the PV modules are connected using TCT configuration, but all PV arrays are arranged based on "Su Do Ku" puzzle pattern. The performance of the system is investigated for different shading patterns and the results show that positioning the modules of the array according to "Su Do Ku" puzzle pattern yields improved performance under partially shaded conditions. However, this method faces a drawbacks due to ineffective dispersion of shade and significant increase in wiring requirements, these disadvantages of the "Su Do Ku" method have been enhanced using a new technique which is proposed by S. Potnure et al [13].

3. Power electronics techniques for enhancing PV power generation:

B. Chong & L. Zhang [14] proposed a new controller design for integrated PV-converter modules under partial shading conditions. The control results showing rapid and stable responses are superior to that obtained by bypass diode structure which is conventionally controlled using perturbation-and-observation method. Furthermore, a new GCPV based on cascaded H-Bridge quasi-z source inverter is presented by [15], the technique is used to verify the multilevel PV interface with AC inverters to enhance the power generation of GCPV systems. E. Koutroulis & F. Blaabjerg [16] proposed a new procedure for tracking the global maximum power point of PV arrays operating under partial shading conditions using D-flip/flop and analog/digital converter strategy. Additionally, a brief comprehensive maximum power point extraction using genetic algorithm is shown in [17].

4. <u>PV fault detection algorithms:</u>

There are various methods used to detect faults in GCPV plants. Some of these methods use
statistical analysis techniques such as t-test [18 & 19] and standard deviation limits [20].
Furthermore, machine learning techniques have been also applied in PV systems for fault
detection purposes. ANN network was used by [21] for detection multiple faults in a PV system
such as faulty PV modules and faulty bypass diodes. S. Silvestre et al [22] proposed a new
procedure for fault detection in PV systems which is based on the analysis of the voltage and
current ratios for the entire GCPV plant.

94 In this work, we present a detailed modelling, comparison and data analysis for multiple PV array 95 configurations including the series (S), parallel (P), series-parallel (SP), total-cross-tied (TCT) and bridge-96 linked (BL) configurations. In order to compare the performance for each PV array configuration, various 97 partial shading and faulty PV conditions have been tested. Several indicators such as short circuit current 98 (I_{sc}), current at maximum power point (I_{mpp}), open circuit voltage (V_{oc}), voltage at maximum power point 99 (V_{mpp}), series resistance (R_s), fill factor (FF) and thermal voltage (V_{te}) have been used to compare the 9100 obtained by the tested partial shading and faulty conditions.

Fig. 1 shows the overall examined PV array configurations, tested case scenarios and all indicators used to compare the performance between each PV array configuration. As can be noticed, the partial shading conditions applied in this paper is not static, which means that the partial shading conditions are either increasing or decreasing among all PV modules. Additionally, in order to test the performance of each PV array configuration under faulty PV conditions, from 1 to 6 Faulty PV modules have been disconnected in order to compare between each PV indicator variations.

From the literature, there is a few data analysis on the indicators variations among partial shading and faulty PV conditions applied to multiple PV array configurations, therefore, the main contribution of this article is the comparison and data analysis of multiple PV array configurations using seven different indicators. The examined indicators has not been fully covered in previously published articles such as [6-10]. Additionally, this research does not only examine several partial shading conditions affecting PV systems but also the modelling and the analysis of several faulty PV conditions (In-active PV modules)

113 affecting various PV array configurations.

114 This paper is organized as follows: Section 2 presents the modelling and simulation for one PV module 115 using MATLAB/Simulink software. Section 3 describes the calculation of the diagnostic indicators, while



Fig. 1. All Listed PV Array Configurations Compared in this Paper, Tested Case Studies and All Indicators Used to Compare the Performance of Each PV Array Configuration

section 4 illustrates the simulation, modelling and data analysis of the examined PV array configurations.Finally, section 5 and section 6 describes the discussion and the conclusion respectively.

118 2. Modelling and simulation of one PV module

In this work, MATLAB/Simulink software is used to model, simulate and analyze the performance of the examined PV modules. Fig. 3(a) shows the equivalent circuit of a PV module. The voltage and the current characteristics of the PV module can be obtained using the single diode model [23] as explained in (1).

122
$$I = I_{ph} - I_o \left(e^{\frac{V + IR_s}{N_s V_t}} - 1 \right) - \left(\frac{V + IR_s}{R_{sh}} \right)$$
(1)

where I_{ph} is the photo-generated current at STC, I_o is the dark saturation current at STC, R_s is the module series resistance, R_{sh} is the panel parallel resistance, N_s is the number of series cells in the PV module and V_t is the thermal voltage and it can be calculated using (2).

$$V_t = \frac{A k T}{q} \tag{2}$$

127 where A the diode ideality factor, k is Boltzmann's constant, T is the module temperature in kelvin and q128 is the charge of the electron.

129 The five parameters model are determined by solving the transcendental equation (1) using Newton-130 Raphson algorithm [24] based only on the datasheet of the available parameters shown in Table I. The 131 power produced by PV module in watts can be easily calculated along with the current (I) and voltage (V) 132 that is generated by equation (1), therefore, P_{theoretical} = IV.

133 Fig 3(b) shows the PV module simulated at standard test conditions (STC):

- Irradiance 1000 W/m², spectrum AM 1.5 G
- PV module temperature 25 °C

136 Using the MATLAB/Simulink software, it is possible to simulate the output voltage, current and the

137 power of the PV module as shown in Fig. 3(c). As an example of simulation, Fig 2(a) and Fig2(b) show

respectively the I-V and P-V curves of one PV module of 60 solar cells obtained with Simulink using the



Fig. 2. Simulation Results of MALTBAL/Simulink model. (a) Photovoltaic I-V Curve, (b) Photovoltaic P-V Curve

model described in Fig. 3(c). In this paper, the solar cell parameters used in the simulation are shown in Table1.



Fig. 3. Photovoltaic Modelling Using MATLAB/Simulink. (a) Equivalent Circuit of a Solar Module, (b) Simulating PV Module under STC, (c) Simulating the Output Voltage, Current and Power of the PV Module

Table 1	
Electrical characteristics of SMT (60)) P PV module
Solar panel electrical characteristics	Value
Peak power	220 W
Voltage at maximum power point (V _{mp})	28.7 V
Current at maximum power point (I_{mp})	7.67 A
Open circuit voltage (V_{oc})	36.74 V
Short circuit current (I_{sc})	8.24 A
Number of cells connected in series	60
Number of cells connected in parallel	1
Series resistance (R_S)	$0.48484 \ \Omega$
Parallel resistance (R _{sh})	258.75Ω
Dark saturation current (I _o)	$2.8 imes 10^{-10} \mathrm{A}$
Ideal diode factor (A)	0.9117
Boltzmann's constant (k)	$1.3806 \times 10^{-23} \mathrm{J.K^{-1}}$

141 3. Calculation of the diagnostic indicators

In order to compare the behavior of various PV array configurations. Firstly, it is required to identify the
 main indicators needed to investigate the change of the PV array configurations behavior. In this paper, a
 comparison between V_{mpp}, V_{oc}, I_{mpp}, I_{sc} and P_{mpp} have been estimated for various PV array configurations.
 Additionally, new diagnostic indicators have been used and briefly explained in this section.

146 3.1 Equivalent thermal voltage (V_{te})

In previous work [25 & 27] an estimation of the thermal voltage of a PV model under partial shadingconditions has been expressed by (3).

149
$$V_{te} = \frac{(2V_{mp} - V_{oc})(I_{sc} - I_{mp})}{I_{mp} - (I_{sc} - I_{mp})\ln(\frac{I_{sc} - I_{mp}}{I_{sc}})}$$
(3)

where V_{mp} is voltage at maximum power point, I_{mp} presents the current at the maximum power point, V_{oc} is the open circuit voltage and I_{sc} is the short circuit current estimated by the I-V or P-V curve of the PV module.

A second commonly used method to estimate the thermal voltage is to evaluate the change of the diode ideality factor *A* of the PV module [26]. This method can be calculated using (4).

$$V_{te} = \frac{N_s A k T}{q}$$
(4)

where N_s is the number of solar cells connected in series, k is the Boltzmann constant, T is the junction temperature in kelvin and q is equal to the charge of an electron.

In this paper, the first method was used to estimate the thermal voltage due to its simplicity and it does not require the estimation of the ideality factor for the PV modules [18]. The estimation of the ideality factor is usually cannot be calculated using the maximum power point tracking units provided in the PV systems. However, the first method does contain all parameters which are normally available to the user of the grid-connected PV (GCPV) plants.

163 The estimation of V_{te} for the PV module used in this paper under various irradiance levels (100~1000 164 W/m²) are shown in Fig. 4. The PV module temperature for all measurements is at STC 25 °C and the 165 solar cell parameters used in the simulation are shown in Table1.



Fig. 4. Thermal Voltage Estimation under Various Irradiance Levels

166 3.2 Fill factor (FF)

167 The fill factor (FF) is a generic diagnostic indicator which is sensitive to power losses due to shading and
168 faulty conditions occurring in PV systems [27]. FF is sufficiently robust to the irradiance change and the
169 temperature levels. FF can be calculated using (5).

 $FF = \frac{I_{mp} V_{mp}}{I_{sc} V_{oc}}$ (5)

171 The fill factor is a good indicator since it depends on the voltage and current changes in the PV modules.
172 Fig. 5(a) shows the I-V curve of the PV module used in this work. Also it shows the location of the parameters used in the calculation of the FF indicator.

174 At STC, the PV module used in this work can be evaluated as shown in (6).

175
$$FF = \frac{I_{mp} V_{mp}}{I_{sc} V_{oc}} = \frac{7.67 \times 28.7}{8.18 \times 36.74} = 73.25\%$$
(6)



176 Fig. 5(b) shows the variations of the FF under various irradiance levels $(100 - 1000 \text{ W/m}^2)$.

Fig. 5. (a) Fill Factor Parameters Estimation Using Photovoltaic I-V Curve, (b) Fill Factor Estimation under Various Irradiance Levels

177 3.3 PV series resistance (R_s)

178 <u>Method 1:</u>

179 One commonly used method to estimate R_s is to evaluate the derivative of the voltage with respect to the 180 current at the V_{oc} . The final expression to approximate the series resistance is described by (7).

$$R_{s,e} = -\frac{dV}{dI} | V \approx V_{oc} = -\frac{V_2 - V_1}{I_2 - I_1} | V \approx V_{oc}$$
(7)

182 where V_2 , V_1 , I_2 and I_1 are the voltage and the current points estimated near to V_{oc} .

183 The value of the series resistance estimated by the derivative may vary with the irradiance the temperature 184 conditions [28]. D. Sara et al [29] proposed a method to translate the value of the estimated R_s to STC in 185 order to mitigate the effect of the irradiance (G) and PV module temperature (T). The expression is 186 illustrated by (8).

187
$$R_s = R_{s,e} + \frac{V_{te}}{I_{sc}} \left(\frac{G}{G_{STC}} \times \frac{T_{STC}}{T} - 1\right)$$

188 (8)

189 where G_{STC} is equal to 1000 W/m² and T_{STC} is equal to 25 °C.

190 As can be noticed, the estimation of the series resistance requires the voltage and the current 191 measurements of at least two point of the I-V curve close to the V_{oc} . The method also requires the value 192 of the irradiance and the PV modules temperature to perform the estimation of the series resistance value.

193 <u>Method 2:</u>

Another method of estimating the series resistance of a PV module is to evaluate the derivative of the voltage with respect to the current at the short circuit and maximum power point, such point is characterized by a current lower, but closer to I_{mpp} and it is denominated as Q. This method was proposed by [21] and used in [27 and 28] for the estimation of R_s . There are two options to calculate Q (9 & 10).

$$Q1 = I_{sc,e} - (0.75 \times I_{mpp})$$
⁽⁹⁾

199
$$Q2 = I_{sc,e} - (0.60 \times I_{mpp})$$

200 where the value of $I_{sc,e}$ is the estimated short circuit current and can be evaluated using (11).

201

204

198

$$I_{sc,e} = \frac{I_{sc}}{K_1} \tag{11}$$

(10)

where K_1 is the ratio between I_{mpp} and I_{sc} and it is assumed as constant value of 0.92 as described by [21].

203 The final expression of estimating the value of the series resistance is expressed by (12).

$$R_{s} = -\frac{dV}{dI} | I \approx Q = -\frac{V_{2} - V_{1}}{I_{2} - I_{1}} | I \approx Q$$
(12)

The evaluation of the series resistance requires at least two points of the I-V curve for the PV module.Furthermore, it is required to measure:

- 207 1. Current at maximum power point (I_{mpp})
- 208 2. Short circuit current (I_{sc})

Fig. 6 shows the value of the series resistance estimated using method 1 and method 2. The estimated values of the R_s are compared with the measured R_s . Therefore, the difference between the measured values with the estimated values can be expressed by (13).

212 $Difference = Estimated R_s - Measured R_s$ (13)

213 Table 2 shows the comparison between the estimated R_s and measured R_s using method 1: at V_{oc} , and

214 method 2: at Q1 and Q2. The minimum average difference is equal to 1.71% obtained for method 1.

215 Therefore, in this paper, method 1 is used for the estimation of R_s .

			Tabl	e 2			
		Difference	between Estim	ated R _s and M	easured R _s		
Irradiance	Measured	Estimated	$R_s(\Omega)$ using	Estimated F	$R_s(\Omega)$ using	Estimated F	$R_s(\Omega)$ using
level	$R_s(\Omega)$	met	hod 1	method	d 2, Q1	metho	d 2, Q2
(W/m^2)		$R_s(\Omega)$	Difference	$R_s(\Omega)$	Difference	$R_s(\Omega)$	Difference
1000	0.48484	0.512558	0.027717	0.532558	0.047718	0.582558	0.097718
900	0.537836	0.545554	0.007718	0.595554	0.057718	0.595554	0.057718
800	0.567762	0.58548	0.017718	0.62548	0.057718	0.70548	0.137718
700	0.623004	0.637755	0.014751	0.681755	0.058751	0.687755	0.064751
600	0.698996	0.706714	0.007718	0.606714	-0.09228	0.816714	0.117718
500	0.789787	0.804505	0.014718	0.837845	0.048058	0.934505	0.144718
400	0.934482	0.9522	0.017718	0.9822	0.047718	1.1322	0.197718
300	1.172762	1.20048	0.027718	1.23448	0.061718	1.31048	0.137718
200	1.688184	1.705902	0.017718	1.729902	0.041718	1.815902	0.127718
100	3.240672	3.25839	0.017718	3.28139	0.040718	3.33839	0.097718
		Average Di	fference (%)	Average Dif	ference (%)	Average Di	fference (%)
		1	.71	3.	69	11	.81



Fig. 6. Evaluating the Series Resistance of a PV Module under Various Irradiance Levels

216 4. Simulation, modelling and data analysis of multiple PV array configurations

217 The aim of this section is to present the multiple PV array configurations used in this study. In order to 218 test the multiple PV array configurations, 24 PV modules were used. Each PV module consists of 60 PV 219 modules connected in series and protected by bypass diodes. The PV modules temperature was fixed at 220 the standard test condition (STC) 25 °C.

4.1 Types of examined PV array configurations

Five common PV array configurations were used in order to examine the main indicators which are
 mostly changeable during the normal operation mode, partial shading and faulty PV conditions. The
 examined PV array configurations are listed as the following:

- 225 1. Series (S) configuration
- 226 2. Parallel (P) configuration
- **227** 3. Series-Parallel (SP) configuration
- **228** 4. Total-Cross-Tied (TCT) configuration
- **229** 5. Bridge-Linked (BL) configuration

230 MATLAB/Simulink software is used to create the listed PV array configurations. Appendix A contains all

231 MATLAB/Simulink software models which are used to configure the grid-connected PV (GCPV)

232 systems. Furthermore, during the simulation all indicators: V_{mpp} , V_{oc} , I_{mpp} , I_{sc} , P_{mpp} , R_s , FF and V_{te} were

saved in a spreadsheet to evaluate the performance of each PV array configuration separately.

4.2 PV array configurations under STC

This section presents the variations of all required indicators at standard test conditions applied to the PV
array configurations. Table 3 shows the value of all indicators for the different PV array configurations.
The main outcomes from the obtained results can be expressed by the following:

- Series configuration: the dominant indicator is the value of the V_{oc}, V_{mp} and the value of the thermal voltage.
- 240
 2. Parallel configuration: I_{sc}, I_{mpp} and the thermal voltage which has the least value across all PV configurations.
- **242** 3. SP, TCT and BL configurations have a common similarity across all indicators.
- 243 4. At STC, the FF for all PV configurations is approximately equal to 73.2%.
- From Table 4 it is possible to evaluate the value of the series resistance across one PV module in the

	Mathematical Calculations of Rs for Various GCPV Plants	
PV array configuration	Mathematical expression for estimating the value of R_s for one PV module in the PV array configuration	
S	R _{s (Obtained from the I-V Curve)}	
	$24_{(total PV module in the PV array configuration)}$	(14)
Р	$R_{s(Obtained\ from\ the\ I-V\ Curve)} imes24_{(total\ PV\ module\ in\ the\ PV\ array\ configuration)}$	(15)
SP, TCT and	$R_{s (Obtained from the I-V Curve)} \times 4$ (number of PV columns)	(16)
BL	6 _(number of PV modules in one PV row "PV String")	

Table 3	3
matical Calculations of R	for Various GCP

245 GCPV systems according to the mathematical expressions listed below in Table 3.

Table 5 shows that the estimation of the series resistance for a single PV module using the mathematical

expressions listed in Table 3 at STC. There is a slightly difference between the real measured R_s values at

248 STC with the calculated R_s using (14-16). The percentage of the average difference between the measured

				Table	4			
Inc	dicators Va	lues Esti	imated fo	or All E	xamined	PV Array Co	onfiguration	ns
PV	I _{sc}	V _{oc}	Impp	V_{mpp}	P _{mpp}	R _s	V _{te}	FF
configuration	n (A)	(V)	(A)	(V)	(W)	(Ω)	(V)	(%)
S	8.177	881.2	7.538	700.3	5279	12.18175	36.2059	73.2608
Р	196.2	36.74	181.4	29.1	5279	0.020116	1.44597	73.2305
SP	32.71	220.3	30.26	174.4	5279	0.757576	8.59957	73.2353
TCT	32.71	220.3	30.33	174	5278	0.757576	8.31149	73.2363
BL	32.71	220.3	30.33	174	5278	0.757576	8.31149	73.2363
				Table 5				
		Estimo	tad D fa) V. Madu	la Omles		
DI	D	Estillia	$\frac{1}{1}$		v Modu		D:00	• .1
PV	$\mathbf{R}_{\mathbf{s}}$	Calc	ulated R	_s for	Measur	ed R_s for	Differenc	the in the
configuration	$(\Omega) \qquad \text{one PV module} \qquad \text{one PV module at}$					estimatic	on of R _s	
			(Ω)		ST	$C(\Omega)$	(%)
S	12.18175	C).507573		0.4	8484	2.273	299
Р	0.020116	0).482772		0.4	8484	-0.20	675
SP	0.757576	0).505051		0.4	8484	2.021	051
TCT	0.757576	0).505051		0.4	8484	2.021	051
BL	0.757576	C).505051		0.4	8484	2.021	051

249 R_s and the calculated R_s is equal to 2.2%.

4.3 Partial shading conditions applied to the PV array configurations

In order to evaluate the behavior of each PV configuration under non-uniform irradiance conditions and to choose the most optimal configuration that provides that highest performance and identifying the main indicators which are changing significantly in each PV configuration, two different shading scenarios and two faulty PV conditions were tested for each PV configuration under a fixed temperature 25 °C.

255 4.3.1 Scenario 1: row level

In this part, the focus will be on the performance of the PV configurations which are affected by a
uniformly and non-uniform shading patterns on a row level (row of PV modules). Fig. 7 shows both
patterns used to evaluate the row shading conditions effects on the PV modules.

As can be noticed from Fig. 7, two different partial shading conditions was performed. The first partial
 shading pattern is applied on a row of PV modules at irradiance level equal to 500 W/m². However, the
 second shading pattern consists of various irradiance levels (200, 400, 600 and 800 W/m²) applied to four
 PV modules.

Fig. 8(a) shows the maximum output power obtained in each PV array configuration under shading
pattern 1. The P configuration shows the maximum output power comparing to all other examined PV
array configurations. The configurations S, SP, TCT and BL provide the same maximum power in each
case.

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	Partial Shad	ing Pattern	1	
500	500	500	500	
W/m ²	W/m ²	W/m ²	W/m ²	
1000	1000	1000	1000	Case 1:First Row 500W/m ⁻
W/m ²	W/m ²	W/m ²	W/m ²	Case 2: First and Second Rows 500W/m ²
1000	1000	1000	1000	
W/m ²	W/m ²	W/m ²	W/m ²	Case 3:First, Second and Third Rows 500W/m ²
1000	1000	1000	1000	
W/m ²	W/m ²	W/m ²	W/m ²	Case 4:First, Second, Third and Fourth Rows 500W/m ²
1000	1000	1000	1000	Correst Filmet Second Third Founds and Files Denne 50000 (m ²
W/m ²	W/m ²	W/m ²	W/m ²	Case 5: First, Second, I nird, Fourth and Fifth Rows 500w/m
1000	1000	1000	1000	
W/m ²	W/m ²	W/m ²	W/m ²	
200	Partial Shad	ing Pattern 600	2 800	
W/m ²	W/m ²	W/m ²	W/m ²	
1000	1000	1000	1000	Case 1: First Row unevenly shaded (pattern 2)
W/m ²	W/m ²	W/m ²	W/m ²	Case 2: First and Second Rows unevenly shaded (nattern 2)
1000	1000	1000	1000	cuse 2.1 list and Second Rows unevenity shaded (parter in 2)
W/m ²	W/m ²	W/m ²	W/m ²	Case 3: First, Second and Third Rows unevenly shaded (pattern 2)
1000	1000	1000	1000	
W/m ²	W/m ²	W/m ²	W/m ²	Case 4:First, Second, Third and Fourth Rows unevenly shaded (pattern 2)
1000	1000	1000	1000	Case 5-First Second Third Fourth and Fifth Dows unevenly shaded (nottern 2)
W/m ²	W/m ²	W/m ²	W/m ²	Case S.rnst, Second, rund, routin and rith Kows uneventy shaded (pattern 2)
1000	1000	1000	1000	
W/m ²	W/m ²	W/m ²	W/m ²	

Fig. 7. Partial Shading Patterns for Scenario 1: Row Level

Fig. 8(b) proves that P configuration has the maximum output power among all other PV arrayconfigurations under shading pattern 2. TCT and BL comes second best choice whereas the seriesconfiguration has the lowest performance.

270 In each shading pattern, the series resistance (R_s) was estimated using method 1 which has been discussed 271 previously in section 3.3. Table 6 shows the estimated R_s for each PV array configuration for shading

271 previously in section 3.3. Table 6 shows the estimated R_s for each PV array configuration for shading 272 pattern 1. Rs estimated for the S configuration is increased by approximate to 1.13 Ω . Additionally, the

estimated series resistance for SP, TCT and BL configurations is increased by approximate to 0.07Ω .

There is a very small amount of change in the series resistance obtained for P configuration, the reduction

275 is only equal to 0.002Ω .



Fig. 8. Partial Shading Patterns for Scenario 1: Row Level. (a) Output Power for Pattern 1, (b) Output power for Pattern 2

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Estimated R _s for th	he Multiple Array Configurations, Scenario 1: Row Level, Pattern 1					
Case #	Estimated $R_s(\Omega)$ for Shading Pattern 1					
	S	Р	SP	TCT	BL	
Case 1	13.33689	0.022147	0.826446	0.826446	0.826446	
Case 2	14.47387	0.023601	0.897666	0.897666	0.897666	
Case 3	15.61524	0.025198	0.966184	0.966184	0.966184	
Case 4	16.7392	0.027174	1.037344	1.037344	1.037344	
Case 5	17.87949	0.029661	1.105705	1.105705	1.105705	
		Table	7			
Estimated R _s for th	e Multiple A	array Configu	urations, Scen	nario 1: Row I	Level, Pattern 2	
Case #	J	Estimated R _s	(Ω) for Shad	ling Pattern 2	2	
	S	Р	SP	TCT	BL	
Case 1	14.05877	0.022279	0.848896	0.827267	0.835422	
Case 2	15.9261	0.023609	0.921404	0.898473	0.906618	
Case 3	17.75884	0.025253	0.990099	0.968992	0.975039	
Case 4	19.604	0.027216	1.053297	1.037775	1.045369	
Case 5	21.42704	0.029775	1.136493	1.109385	1.117318	

Table 6

276 Table 7 shows the estimated Rs for partial shading pattern 2. The S configuration has an increase by 1.8 Ω

277 in the R_s . Moreover, the parallel configuration has the lowest rate of change in the R_s which is approximate equal to 0.002. SP, TCT and BL configurations has an increase of 0.07 Ω in the R_s among all 278

279 testes cases in the row level partial shading conditions.

280 The FF indicator was also calculated for each examined partial shading patterns. Fig. 9(a) and Fig 9(b) 281 illustrates the FF variations among the tested GCPV systems for shading pattern 1 and shading pattern 2

282 respectively. The P configuration shows that the FF has a value close to 73% among all tested case 283 scenarios. However, a reduction in the FF was obtained across all other PV array configurations.

284 The Thermal voltage V_{te} across each PV array configuration during the tested partial shading pattern1 and 285 pattern 2 are shown in Fig. 9(c) and Fig. 9(d) respectively. The threshold values of the V_{te} is taken from 286 Table 4. It is evident that the V_{te} for P configuration is approximate equal to 1.44V which is exactly the 287 same as the P configuration V_{te} threshold.

288 S, SP, TCT and BL configurations show that the value of V_{te} is lower than the value of V_{te} threshold in low partial shading conditions if: reduction in irradiance < 6000 W/m². However, in most partial shading 289 290 conditions examined in this section, the obtained value of the V_{te} is greater than the value of V_{te} threshold 291 if: reduction in the irradiance $\geq 6000 \text{ W/m}^2$.

- 292 From this section, the obtained results could be illustrated as the following:
- 293 R_s could be a good indicator to predict/estimate partial shading conditions for S, SP, TCT and BL 294 configurations. However, R_s cannot be used with P configuration since it does not change 295 significantly during the increase/decrease of the partial shading conditions applied PV system.
- 296 FF has a significant drop in its value while increasing the partial shading in the S, SP, TCT and 297 BL configurations. This is not a proper indicator to be used with P configuration since it does not 298 change among all tested partial shading conditions.
- 299 When the reduction in the irradiance is greater or equal to 6000 W/m^2 , the value of the V_{te} in most partial shading conditions is greater than the value of V_{te} threshold for S, SP, TCT and BL 300 301 configurations. However, P configurations shows that the value of the V_{te} is almost equal to the value of V_{te} threshold. 302



Fig. 9. FF and V_{te} Variations for Scenario 1: Row Level. (a) Fill Factor Variations for Pattern 1, (b) Fill Factor Variations for Pattern 2, (c) V_{te} Variations for Pattern 1, (d) V_{te} Variations for Pattern 2

303 4.3.2 Scenario 2: column level

304 This section is created to check the variations of the R_s , V_{te} , FF indicators when a partial shading 305 conditions occurred in the PV array configuration on a column level (column of PV modules).

Fig. 10 shows two different partial shading patterns examined. The first partial shading pattern is applied
 on a column of PV modules at irradiance level equal to 500 W/m². However, the second shading pattern
 consists of various irradiance levels (100, 200, 500, 600, 800 and 900 W/m²) applied to six PV modules.

Fig. 11(a) shows the maximum output power obtained in each PV array configuration under shading pattern 1. P, SP, TCT and BL configurations shows approximately the same maximum output power.
Furthermore, S configuration provides the minimum output power during all examined case scenarios used in shading pattern 1. On the other hand, the maximum output power obtained from shading pattern 2 is illustrated in Fig. 11(b). The maximum output power could be evaluated at the P configuration.
However, S configuration remains the worst configuration.

315 In each shading pattern (pattern 1 and 2), the series resistance (R_s) was estimated. Table 8 shows the 316 estimated R_s for each PV array configuration for shading pattern 1. As can be noticed, Rs estimated for 317 the S configuration is increasing by approximate to 1.68 Ω . This result can be calculated using the 318 difference between case1 and case2, where the values of R_s are taken from the measured data explained in 319 table 2:

Estimated $R_s = Number of PV modules_{(at partial shading condition)} \times R_s(at partial shading condition)$

$$\begin{aligned} Case1: Estimated \ R_s &= \left(\ 6_{\left(\ at \ 500\frac{W}{m^2} \right)} \ \times \ 0.789787 \right) + \left(18_{\left(\ at \ 1000\frac{W}{m^2} \right)} \ \times \ 0.48484 \right) = 13.47 \ \Omega \end{aligned}$$
$$Case2: Estimated \ R_s &= \left(\ 12_{\left(\ at \ 500\frac{W}{m^2} \right)} \ \times \ 0.789787 \right) + \left(12_{\left(\ at \ 1000\frac{W}{m^2} \right)} \ \times \ 0.48484 \right) = 15.30 \ \Omega \end{aligned}$$

320 Differance = $Case2 - Case1 = 15.3 - 13.47 = 1.83 \Omega \approx 1.68 \Omega$ Obtianed by the I – V cuve

I	Partial Shad	ling Pattern	1
500	1000	1000	1000
W/m^2	W/m ²	W/m^2	W/m^2
500	1000	1000	1000
W/m^2	W/m ²	W/m^2	W/m^2
500	1000	1000	1000
W/m^2	W/m^2	W/m^2	W/m^2
500	1000	1000	1000
W/m^2	W/m^2	W/m^2	W/m^2
500	1000	1000	1000
W/m^2	W/m^2	W/m^2	W/m^2
500	1000	1000	1000
W/m^2	W/m^2	W/m^2	W/m^2

F	artial Shad	ing Pattern	12
100	1000	1000	1000
W/m^2	W/m^2	W/m^2	W/m^2
200	1000	1000	1000
W/m^2	W/m^2	W/m^2	W/m^2
500	1000	1000	1000
W/m^2	W/m^2	W/m^2	W/m^2
600	1000	1000	1000
W/m^2	W/m^2	W/m^2	W/m^2
800	1000	1000	1000
W/m^2	W/m^2	W/m^2	W/m^2
900	1000	1000	1000
W/m^2	W/m^2	W/m^2	W/m^2



Case 1:First Column unevenly shaded (pattern 2)
Case 2:First and Second Columns unevenly shaded (pattern 2)
Case 3: First, Second and Third Columns unevenly shaded (pattern 2)
Case 4:First, Second, Third and Fourth Columns unevenly shaded (pattern 2)

Fig. 10. Partial Shading Patterns for Scenario 2: Column Level



Fig. 11. Partial Shading Patterns for Scenario 2: Column Level. (a) Output Power for Pattern 1, (b) Output power for Pattern 2

321 Additionally, the estimated series resistance for SP, TCT and BL configurations is increasing by approximate to 0.12 Ω . However, the parallel configuration remains at nearly constant series resistance 322 323 between $0.02 - 0.03 \Omega$.

324 For the second shading pattern (non-uniform irradiance) the estimated R_s for SP, TCT and BL 325 configurations is increasing by 0.3Ω . The parallel configuration remains at the same R_s which is between 326 $0.02 - 0.03 \Omega$. Similarly, the estimated series resistance for S configuration is increasing by 4.4 Ω while 327 increasing the applied partial shading on the PV array configuration, this can be seen in Table 9 and 328 described by the following mathematical calculations, where the values of R_s are taken from the measured 329 data explained in table 2:

Measured $R_s = Number of PV modules_{(at partail shading condition)} \times R_{s(at partial shading condition)}$

$$\begin{aligned} \text{Case1: Measured } R_{s} \\ &= \left(1_{\left(at\ 100\frac{W}{m^{2}}\right)} \times 3.241\right) + \left(1_{\left(at\ 200\frac{W}{m^{2}}\right)} \times 1.688\right) + \left(1_{\left(at\ 500\frac{W}{m^{2}}\right)} \times 0.789787\right) \\ &+ \left(1_{\left(at\ 600\frac{W}{m^{2}}\right)} \times 0.6988\right) + \left(1_{\left(at\ 800\frac{W}{m^{2}}\right)} \times 0.5677\right) + \left(1_{\left(at\ 900\frac{W}{m^{2}}\right)} \times 0.5378\right) \\ &+ \left(18_{\left(at\ 1000\frac{W}{m^{2}}\right)} \times 0.48484\right) = 16.25\ \Omega \end{aligned}$$

$$\begin{aligned} \text{Case2: Measured } R_{s} \end{aligned}$$

Case2: Measured R_s

$$= \left(2_{\left(at\ 100\frac{W}{m^{2}}\right)} \times 3.241\right) + \left(2_{\left(at\ 200\frac{W}{m^{2}}\right)} \times 1.688\right) + \left(2_{\left(at\ 500\frac{W}{m^{2}}\right)} \times 0.789787\right) + \left(2_{\left(at\ 600\frac{W}{m^{2}}\right)} \times 0.6988\right) + \left(2_{\left(at\ 800\frac{W}{m^{2}}\right)} \times 0.5677\right) + \left(2_{\left(at\ 900\frac{W}{m^{2}}\right)} \times 0.5378\right) + \left(12_{\left(at\ 1000\frac{W}{m^{2}}\right)} \times 0.48484\right) = 20.865\ \Omega$$

		I able	0		
Estimated R _s for th	the Multiple Array Configurations, Scenario 2: Column Level, Pattern 1				
Case #		Estimated R _s	(Ω) for Shace	ling Pattern 1	
	S	Р	SP	TCT	BL
Case 1	13.8754	0.022921	0.818197	0.818197	0.818197
Case 2	15.55936	0.025198	0.898957	0.898957	0.898957
Case 3	17.26519	0.028329	1.012146	1.012146	1.012146
Case 4	18.93581	0.033034	1.176471	1.176471	1.176471

Table 9

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Case #		Estimated R _s	(Ω) for Shace	ling Pattern 2	,
	S	Р	SP	TCT	BL
Case 1	16.85772	0.022861	0.83675	0.819403	0.823045
Case 2	21.33106	0.025054	0.961538	0.918274	0.929195
Case 3	25.75992	0.02809	1.186662	1.106195	1.119821
Case 4	30.08424	0.032468	1.845018	1.845359	1.845359

Fig. 12(a) and Fig. 12(b) illustrates the FF variations among the tested PV array configuration systems for shading pattern 1 and shading pattern 2 respectively. Shading pattern 1 shows that P, SP, TCT and BL configurations have a value of FF approximate to 74% among all tested cases. However, a reduction in the FF was only obtained across the S configuration. Shading pattern 2 (non-uniform shading) shows a different results comparing to shading pattern 1 (uniform shading), these results could be illustrated as the following:

- The estimated FF for the P configuration under non-uniform and uniform shading patterns are exactly equal.
- There is a huge reduction in the FF for S, SP, TCT and BL configurations in the non-uniform shading pattern conditions.
- Fig. 12(a) shows that the value of the FF for the S configuration at case 4 is equal to 74% because in this particular shading case, the percentage of shading among all PV modules are equal.
- The Thermal voltage V_{te} across each PV array configuration during the tested partial shading pattern1 and pattern 2 are shown in Fig. 12(c) and Fig. 9(d) respectively. The threshold values of the V_{te} is taken from Table 4. It is evident that the V_{te} for P configuration is approximate equal to 1.44V which is exactly the same as the P configuration V_{te} threshold. The estimated values of the V_{te} for SP, TCT and BL configurations are exactly the same as the V_{te} threshold during shading pattern 1. However, the estimated V_{te} for S configuration is greater than the value of the V_{te} threshold if: Reduction in irradiance ≥ 6000 W/m².
- **350** Fig. 12(d) shows that the estimated V_{te} is exactly the same as the V_{te} threshold for shading pattern 2. SP,
- **351** TCT and BL configurations proves that when the reduction in the irradiance is greater than 2900 W/m^2
- the estimated value of V_{te} is always greater than V_{te} threshold. Moreover, S configuration shows that the value of the V_{te} is greater than V_{te} threshold if: Reduction in irradiance $\ge 6000 \text{ W/m}^2$.
- In conclusion, this section shows some results on the performance of the examined PV array
 configurations under uniform and non-uniform partial shading patterns. The main findings could be
 illustrated as the following:
- Under uniform shading patterns which effects on a column of PV modules, the output power for
 P, SP, TCT and BL configurations are exactly the same. Furthermore, the S configuration shows
 the least output power among all PV array configurations.
- Under non-uniform shading patterns which effects on a column of PV modules, the optimum output power was estimated for the parallel configuration.
- The series resistance R_s is a good indicator for detecting/predicting partial shading conditions for S, SP, TCT and BL configurations since the value of the R_s change significantly while increasing the partial shading conditions applied to the PV configurations.
- The Fill factor (FF) indicator could be used with SP, TCT and BL configurations only under non-uniform irradiance conditions. Furthermore, there is a large drop in the value of FF for the S configuration under uniform and non-uniform irradiance levels.

The value of the V_{te} could be used as a proper indicator for detecting partial shading conditions for S, SP, TCT and BL configuration under non-uniform partial shading conditions affecting the GCPV plants.



Fig. 12. FF and V_{te} Variations for Scenario 2: Column Level. (a) Fill Factor Variations for Pattern 1, (b) Fill Factor Variations for Pattern 2, (c) V_{te} Variations for Pattern 1, (d) V_{te} Variations for Pattern 2

371 *4.3.3 Scenario 3: faulty PV modules*

- **372** This section is created to check the variations of the R_s , V_{te} , FF indicators when a faulty PV modules have **373** been a raised in the PV array configurations.
- Two faulty scenarios were carried out to estimate the output performance for each PV array configurationunder faulty PV modules. Fig. 13 illustrates both cases which can be described by the following:
- Row level: six different scenarios were tested to estimate the faulty PV modules which are disconnected (short circuit the PV module) from a row of the PV array configuration.
- 3782. Column level: four different scenarios were tested to estimate the faulty PV modules which are disconnected from the entire column of the PV array configuration.
- The PV modules irradiance and temperature level are at standard test conditions: 1000W/m² and 25 °C
 respectively.
- Fig. 14(a) and Fig 14(b) shows that the configurations S and P provides the highest maximum output
 power among all PV array configurations. The second maximum output power is achieved by the SP
 configuration. However, the minimum output power is estimated for the TCT configuration among all
 faulty PV case scenarios.
- **386** The estimated series resistance R_s for the row-level PV faulty conditions are illustrated in Table 10. The S **387** configuration shows that R_s is decreasing by 0.49 Ω while disconnecting one PV module. This result is **388** approximate equal to the measured value of R_s among one PV module (0.48484 Ω) under STC as shown **389** previously in Table 5.
- 390 The estimated R_s for the P configuration among all faulty scenarios is approximately equal to 0.02 Ω . The 391 value of R_s when a PV string is disconnected from the PV array configuration is equal to 1.007 Ω for SP, 302 TCT and PL configurations this value aloud be calculated using (16) as the following:
- **392** TCT and BL configurations, this value cloud be calculated using (16) as the following:
- 393 $Estimated R_s for one PV module = \frac{R_s (Obtained from the I-V Curve) \times 3 (number of PV columns)}{6 (number of PV modules in one PV row "PV String")}$

$$0.48484 = \frac{R_{s (Obtained from the I-V curve)} \times 3 (Since one PV string is completly disconnected)}{6}$$

 $R_{s \ (Obtained \ from \ the \ I-V \ Curve)} = 0.97 \ \Omega \approx 1.007 \ \Omega$

The estimated series resistance R_s for the column-level PV faulty conditions are illustrated in Table 11. As can be noticed that the value of R_s in the S and SP configurations is decreased while increasing the

396 number of faulty PV modules. The estimated R_s for TCT and BL is increasing for the first three PV faulty

- 397 conditions. However, the estimated R_s is equal to 0.63 Ω when disconnecting an entire PV column form
- **398** the SP, TCT and BL array configurations. This result could be estimated using (16) as the following:

399
$$Estimated R_s for one PV module = \frac{R_s (Obtained from the I-V Curve) \times 4 (number of PV columns)}{5 (number of PV modules in one PV row "PV String")}$$

$$0.48484 = \frac{R_{s (Obtained from the I-V Curve)} \times 4 (Since one PV string is completely disconnected)}{-}$$

5

 $R_{s \ (Obtained \ from \ the \ I-V \ Curve)} = \ 0.61 \ \Omega \ \approx \ 0.63 \ \Omega$







Fig. 14. Output Power for Scenario 3: Faulty PV Modules. (a) Output Power for Pattern 1, (b) Output power for Pattern 2

Fig. 15(a) and Fig. 15(b) illustrates the FF variations among the tested PV array configurations using
faulty conditions: row-level and column level respectively. Row-level PV faulty conditions show that S, P
and TCT configurations have a value of FF approximate to 73.2% among all tested scenarios. However, a
reduction in the FF was only obtained across the SP and BL configurations.

To S reduction in the TT was only obtained across the ST and BE configurations.

404 The column-level PV faulty conditions shows that the FF for the S and P configuration remains at 73.2%.

405 Furthermore, there is a huge reduction in the estimated FF for both TCT and BL configurations. The only

406 configuration which has an increase in the estimated values of the FF was obtained for the SP

407 configuration.

408 As shown in Fig. 15(a) at case 6 (Faulty PV string) the estimated value of the FF across all PV array
409 configurations is equal to 73.2%. Similar results obtained for case4 (faulty column) illustrated in Fig
410 15(b).

411 The Thermal voltage V_{te} estimated for each PV array configuration under faulty PV modules conditions 412 (row-level and column-level) are shown in Fig. 15(c) and Fig. 9(d) respectively. From Fig. 15(c), it is 413 evident that V_{te} for P configuration is equal to 1.36V among all PV faulty conditions, this result is 414 approximately equal to P configuration V_{te} threshold: 1.44V. The estimated value of the V_{te} for S, SP, 415 TCT and BL configurations is decreased while increasing the number of faulty PV modules in the PV 416 array configuration due to the decrease in the V_{mp} . Despite the decrease of V_{oc} , the value of V_{mp} is 417 multiplied by a factor of 2, therefore, V_{te} is also decreasing. This results can be expressed by the 418 following:

419
$$V_{te} \downarrow = \frac{(2V_{mp}\downarrow \downarrow - V_{oc}\downarrow)(I_{sc} - I_{mp})}{I_{mp} - (I_{sc} - I_{mp})\ln(\frac{I_{sc} - I_{mp}}{I_{sc}})}$$

420 Different results obtained at case6 in Fig. 15(c), where a faulty PV string occurred in each PV 421 configuration. The value of V_{te} for the SP, TCT and BL is increased because the value of the I_{sc} and I_{mp} is

422 decreased:

423
$$V_{te} \uparrow = \frac{(2V_{mp} \downarrow \downarrow - V_{oc} \downarrow)(I_{sc} \downarrow - I_{mp} \downarrow)}{I_{mp\downarrow} - (I_{sc} \downarrow - I_{mp} \downarrow) \ln\left(\frac{I_{sc} \downarrow - I_{mp} \downarrow}{I_{sc\downarrow}}\right)} denominator is decreasing more than numerator$$

424 Similar results obtained for the estimated V_{te} in the column-level faulty PV conditions as shown in Fig 425 15(d). The main findings of this section can be listed as the following:

- When the number of faulty PV modules in increasing the estimated R_s is decreasing in S, SP TCT and BL configurations.
- The FF for the S and P configurations among all faulty PV conditions remains at 73.2%.
- The estimated value of V_{te} for S, SP, TCT and BL configurations is decreased while increasing
 the number of faulty PV modules. However, in case of the faulty PV string occurred in the PV
 system, the value of the V_{te} is increased only in SP, TCT and BL configurations.

432 • P configuration has approximately constant levels of FF and V_{te} among all tested PV faulty conditions.

 Table 10

 Estimated R_s for the Multiple Array Configurations, Scenario 3: PV Faulty Conditions, Row Level

Case #		Е	Estimated R_s (C	2)	
	S	Р	SP	TCT	BL
Case 1	11.57273	0.022096	0.800641	0.631313	0.829876
Case 2	11.08033	0.023095	1.01688	0.505306	0.591541
Case 3	10.58574	0.024196	0.889442	0.379219	0.596659
Case 4	10.08065	0.025408	0.596659	0.253936	0.333778
Case 5	9.581603	0.026748	0.299043	0.128304	0.298151
Case 6	9.077156	0.028226	1.00776	1.00776	1.00776

T 1	1.1.	11	
1 a	ble	11	

Estimated R_s for the Multiple Array Configurations, Scenario 3: PV Faulty Conditions, Column Level

Case #		E	Estimated R_s (C	2)	
	S	Р	SP	TCT	BL
Case 1	11.57273	0.022096	0.800641	0.631313	0.829876
Case 2	11.08033	0.023095	0.764526	0.884173	0.913242
Case 3	10.58574	0.024196	0.693481	1.135203	1.135203
Case 4	10.08065	0.025408	0.631313	0.631313	0.631313



Fig. 15. FF and V_{te} Variations for Scenario 3: Faulty PV Conditions. (a) Fill Factor Variations for Row Level PV Faulty Conditions, (b) Fill Factor Variations for Column Level PV Faulty Conditions, (c) V_{te} Variations for Row Level PV Faulty Conditions, (d) V_{te} Variations for Column Level PV Faulty Conditions

435 5. Discussion

436 In this paper a brief modelling, simulation and data analysis of various partial shading and PV faulty 437 modules conditions have been discussed. Multiple diagnostic indicators have been used to compare the 438 performance of each PV array configuration such as short circuit current (I_{sc}), current at maximum power 439 point (I_{mpp}), open circuit voltage (V_{oc}), voltage at maximum power point (V_{mpp}), series resistance (R_s), fill 440 factor (FF) and thermal voltage (V_{te}). Few of these indictors have been demonstrated by F. Belhachat [6].

441 However, the partial shading conditions applied in this paper is not static as shown in [6, 7, 9 and 13], 442 which means that the partial shading conditions are either increasing or decreasing among all PV 443 modules. Additionally, in order to test the performance of each PV array configuration under faulty PV 444 conditions, from 1 to 6 Faulty PV modules have been disconnected in order to compare between each PV 445 indicator variations, this scenario has been demonstrated in section 4.3.3. Currently, there are few 446 research articles which combines between faulty PV conditions with multiple PV array configurations. 447 Therefore, this section is one of the major contribution for this paper.

448 The obtained results of this research can be divided into four main categories:

449	1 PV array configurations under standard test condition (STC).
450	• The S. P. SP. TCT and BL configurations provide the same maximum output power
451	• FE for all PV array configurations is approximately equal to 73.2%
452	 New mathematical expressions have been derived for estimating the value of the series
453	resistance R across one PV module in all tested PV array configurations
454	Teststance R_s across one 1° module in an ested 1° array configurations.
455	2. PV array configurations under uniform partial shading conditions:
456	• P configuration provides the maximum output power when one to five rows or/and one to
457	four columns are completely shaded.
458	• S SP TCT and BL configurations have an increase of the R, while increase the uniform
459	shading across the PV modules. While P configuration series resistance remains at the
460	same value which is approximate to 0.02 Ω .
461	• FF for the S, SP, TCT and BL configurations have a significant drop in its value while
462	increasing the uniform partials shading condition applied to a row of PV modules.
463	However, the P configuration FF remains at a threshold of 74%.
464	• The value of V_{te} is not a proper indicator for predicting/estimating the change in the
465	partial shading conditions for S, SP, TCT and BL since it does not change among all
466	tested uniform partial shading conditions.
467	
468	3. PV array configurations under non-uniform partial shading conditions:
469	• P configuration provides the maximum output power when one to five rows and/or one to
470	four columns are completely shaded. Furthermore, TCT configuration provided the
471	second optimum output power among all other PV array configurations.
472	• S, SP, TCT and BL configurations have an increase of the R _s while increase the non-
473	uniform shading across the PV modules. While P configuration series resistance remains
474	at the same value which is approximate to 0.02 Ω .
475	• SP, TCT and BL configurations proves that when the reduction in the irradiance is greater
476	than 2900 W/m ² the estimated value of V_{te} is always greater than V_{te} threshold.
477	Moreover, S configuration shows that the value of the V_{te} is greater than V_{te} threshold if:
478	Reduction in irradiance $\geq 6000 \text{ W/m}^2$.

479	4.	PV ar	ray configurations	under faulty PV conditions:
480 481 482		•	P configuration faulty in a row of column of PV m	provides the maximum output power when one to five PV modules are of PV modules and when one to four PV modules are disconnected from a nodules in the PV array configuration.
483		•	The estimation	of the R_s of a single PV module in the PV array configurations can be
484			calculated using	the following mathematical expression:
485			S configuration	$R_{s(ObtainedfromtheI-VCurve)}$
486				$24_{(total PV module in the PV array configuration)}$
487			-	
488			P configuration	$R_{s(ObtainedfromtheI-VCurve)} imes 24_{(totalPVmoduleinthePVarrayconfiguration)}$
489				
490			SP, TCT and BL	$R_{s(Obtained from the I-V Curve)} \times 4$ (number of PV columns)
491			configurations	6 (number of PV modules in one PV row "PV String")
492				(number of 17 modules in one 17 fow 17 string)
493			m	
494			ated value of V _t	e for S, SP, TCT and BL configurations is decreased while increasing the
495			number of fault	y PV modules. However, in case of faulty PV string occurred in the PV
496			system, the valu	e of the $V_{t_{a}}$ is increased only in SP. TCT and BL configurations.
497		•	The FE for the S	S and P configurations among all faulty PV conditions remains at 73.2%
498			However for	all other PV configurations the estimated value of the FF is either
499			increasing or de	creasing.

From the obtained results, it is evident that the variations of I_{sc} , I_{mpp} , V_{oc} , and V_{mpp} are not shown. This is because the value of these indicators have been widely discussed by many research articles such as [6, 7, 9 and 13]. However, all listed references does not include the increase or decrease of shading patterns among all PV configurations, additionally, there are few of discussions about faulty PV modules in multiple PV array configurations.

Table 12, 13 and 14 illustrates the variations for all indicators used in this article among all examined partial shading and faulty PV conditions in the S, P, SP, TCT and BL PV array configurations. Three different symbols are used to show whether the value of the indicator has an " \downarrow " decrease, " \uparrow " increase, "-" no change in its value and $\downarrow\uparrow$ decrease or increase in the value of the indicator. A brief discussion of the indicators R_s, FF and V_{te} are is available in section 4.

510 The S, SP, TCT and BL configurations have always a reduction in the value of V_{oc} while increasing the 511 uniform, non-uniform shading conditions and increasing the number of faulty PV modules. The P 512 configuration has a reduction in the V_{oc} among all shading patterns, however, V_{oc} remains constant while 513 increasing or decreasing the number of faulty PV modules.

514 In most tested conditions, the value of the I_{sc} has no change for the S, SP, TCT and BL configurations. 515 The P configuration proves that the value of I_{sc} is always decreasing while increasing the uniform, non-516 uniform shading conditions and increasing the number of faulty PV modules.

517 The voltage at maximum power point (V_{mpp}) is not a proper indicator for estimating/predicting partial 518 shading conditions or/and faulty PV modules in the S, SP, TCT and BL configuration because in each 519 tested condition the value of V_{mpp} is either increased or decreased. However, this comment is not 520 applicable for the P configuration because the value of the V_{mpp} is always decreasing while increasing the 521 partial shading conditions applied to the PV plant.

522	The last indicator, I _{mpp} is a proper indicator to estimate/predict partial shading conditions in all examined
523	PV array configurations since the value of the indicator is decreasing while increasing shading conditions.
524	The value of I_{mpp} does not change while increasing/decreasing number of faulty PV modules in S, SP,

525 TCT and BL configurations. However, it does change significantly for the P configuration.

Scenario	PV array configurations													
				S					P					
	Isc	I _{mpp}	V _{oc}	V _{mpp}	R _s	FF	V _{te}	Isc	Impp	V _{oc}	V _{mpp}	Rs	FF	V _{te}
Increasing uniform shading on PV row	-	Ļ	\downarrow	$\downarrow\uparrow$	1	\downarrow	$\downarrow\uparrow$	Ļ	Ļ	\downarrow	Ļ	-	-	-
Increasing non-uniform shading on PV row	-	\downarrow	\downarrow	↓↑	↑	\downarrow	↓↑	↓	\downarrow	\downarrow	\downarrow	-	-	-
Increasing uniform shading on PV column	-	Ļ	Ļ	↓↑	1	$\downarrow\uparrow$	$\downarrow\uparrow$	↓	Ļ	Ļ	Ļ	-	-	-
Increasing non-uniform shading on PV column	-	Ļ	Ļ	$\downarrow\uparrow$	1	Ļ	Ļ	↓	Ļ	Ļ	Ļ	-	-	-
Increasing faulty PV modules in PV row	-	-	Ļ	\downarrow	\downarrow	-	\downarrow	↓	Ļ	-	-	1	-	\downarrow
Increasing faulty PV modules in PV column	-	-	\downarrow	\downarrow	\downarrow	-	\downarrow	↓	Ļ	-	-	1	-	\downarrow

 Table 12

 Change in the Estimated Indicators on Each PV Array Configuration

						/								
					Ta	ble 13	;							
Ch	ange	in the	Estim	ated In	dicate	ors on	Each	PV A	Array C	Config	uration			
Scenario						PV a	array c	onfig	guratio	ns				
				SP							TCT	1		
	Isc	I _{mpp}	V _{oc}	V _{mpp}	R _s	FF	V _{te}	Isc	I _{mpp}	V _{oc}	V_{mpp}	R _s	FF	V _{te}
Increasing uniform shading on PV row	-	Ļ	\downarrow	↓↑	↑	$\downarrow\uparrow$	1	-	Ļ	\downarrow	↓↑	ſ	\downarrow	$\downarrow\uparrow$
Increasing non-uniform shading on PV row	-	\downarrow	↓	↓↑	Ţ	\downarrow	$\downarrow\uparrow$	-	\downarrow	\downarrow	$\downarrow\uparrow$	Ţ	\downarrow	$\downarrow\uparrow$
Increasing uniform shading on PV column	-	\downarrow	Ļ	Ļ	ſ	-	-	↓	Ļ	\downarrow	$\downarrow\uparrow$	ſ	-	-
Increasing non-uniform shading on PV column	-	Ļ	Ļ	\downarrow	Ţ	\downarrow	↓↑	↓	\downarrow	Ļ	$\downarrow\uparrow$	Ţ	\downarrow	↓↑
Increasing faulty PV modules in PV row	-	-	Ļ	Ļ	↓↑	\downarrow	Ļ	-	-	\downarrow	Ļ	\downarrow	-	\downarrow
Increasing faulty PV modules in PV column	-	-	Ļ	\downarrow	↓	1	\downarrow	-	-	\downarrow	Ļ	\downarrow	\downarrow	\downarrow

		mulcat	ors on	Each P	v All	ay Con	ingulation	
Scenario			PV	array co	onfigu	ration		
				В	L			
	I _{sc}	Impp	V _{oc}	V _{mpp}	R _s	FF	V _{te}	
Increasing uniform shading on PV row	-	Ļ	Ļ	$\downarrow\uparrow$	ſ	Ļ	$\downarrow\uparrow$	
Increasing non-uniform shading on PV row	-	\downarrow	\downarrow	$\downarrow\uparrow$	ſ	\downarrow	$\downarrow\uparrow$	
Increasing uniform shading on PV column	Ļ	Ļ	Ļ	Ļ	ſ	-	-	
Increasing non-uniform shading on PV column	Ļ	\downarrow	\downarrow	$\downarrow\uparrow$	ſ	\downarrow	$\downarrow\uparrow$	
Increasing faulty PV modules in PV row	-	-	Ļ	Ļ	Ļ	↓↑	↓	
Increasing faulty PV modules in PV column	-	-	\downarrow	\downarrow	↓↑	\downarrow	\downarrow	

 Table 14

 Change in the Estimated Indicators on Each PV Array Configuration

526 6. Conclusion

527 In this paper, multiple PV array configurations including series (S), parallel (P), series-parallel (SP), total-528 cross-tied (TCT) and bridge-lined (BL) have been tested under various partial shading and faulty 529 photovoltaic (PV) conditions. Several indicators such as short circuit current (I_{sc}), current at maximum 530 power point (I_{mpp}), open circuit voltage (V_{oc}), voltage at maximum power point (V_{mpp}), series resistance 531 (R_s), fill factor (FF) and thermal voltage (V_{te}) have been used to compare the obtained results from the 532 partial shading and PV faulty conditions. MATLAB/Simulink software is used to perform the simulation 533 and data analysis for each examined PV array configuration.

The variations for all indicators across all PV array configurations have been reported and compared
briefly. Additionally, new mathematical expressions have been derived to estimate the value of the series
resistance across a single PV module in each PV array configuration under standard test conditions (STC)
and faulty PV modules.

Finally, this study gives a useful information on the main parameters that could be used for
estimating/predicting partial shading conditions in all examined PV array configurations. Therefore, the
results obtained from this study could be enhanced by creating a generic algorithm using machine
learning techniques for detecting faulty PV modules in multiple PV array configurations or/and creating
a reconfigurable PV array system to improve the power generation in grid-connected PV (GCPV) plants.

543 7. Acknowledgment

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546 Appendix A. MATLAB/Simulink model for the examined PV array configurations.

Series (S) Configuration:



Parallel (P) Configuration:





Series-Parallel (SP) Configuration:

Total-Cross-Tied (TCT) Configuration:



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Bridge-Linked (BL) Configuration:



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Highlights

- Analysing multiple photovoltaic (PV) array configurations under partial shading and faulty PV conditions.
- Seven Indicators have been examined including I_{sc} , I_{mpp} , V_{oc} , V_{mpp} , R_s , FF and V_{te} .
- New mathematical calculations for estimating the series resistance across one PV module in a PV array configuration is proposed.